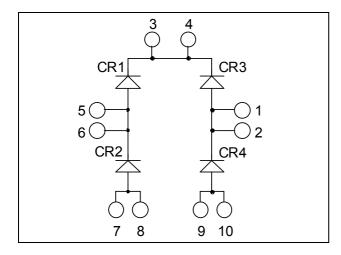
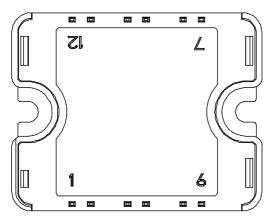


# Fast Diode Full Bridge Power Module







All multiple inputs and outputs must be shorted together 3/4; 5/6; 7/8; 1/2; 9/10

### **Application**

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

#### **Features**

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

#### Absolute maximum ratings

Symbol	Parameter				Max ratings	Unit
$V_R$	Maximum DC reverse Voltage			1200	V	
$V_{RRM}$	Maximum Peak Repetitive Revers	e Voltage			1200	<b>v</b>
$I_{F(AV)}$	Maximum Average Forward	D 4	500/	$T_C = 25$ °C	43	
	Current	Duty cycl	e = 50%	$T_C = 80$ °C	30	A
$I_{FSM}$	Non-Repetitive Forward Surge Cu	irrent 8.3ms		$T_J = 45^{\circ}C$	210	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 30A$			2.6	3.1	
		$I_F = 60A$			3.2		V
		$I_F = 30A$	$T_{j} = 125^{\circ}C$		1.8		
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1200V$ $T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$	$T_i = 25^{\circ}C$			100	^
			$T_j = 125$ °C			500	μΑ
$C_{T}$	Junction Capacitance	$V_R = 200V$			36		pF

**Dynamic Characteristics** 

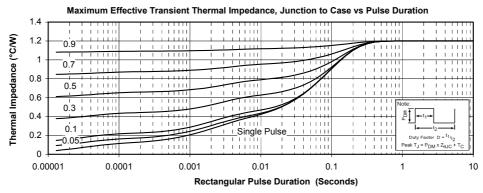
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25^{\circ}C$		300		- ns
r <sub>rr</sub>			$T_{j} = 125^{\circ}C$		380		
$Q_{rr}$	Reverse Recovery Charge $ \begin{array}{c} I_F = 30A \\ V_R = 800V \\ di/dt = 200A/\mu s \end{array} $	$T_j = 25^{\circ}C$		360		nC	
Qrr		$V_R = 800V$ $di/dt = 200A/\mu s$	$T_{i} = 125^{\circ}C$		1700		ne
ī	Reverse Recovery Current		$T_j = 25^{\circ}C$		4		A
$I_{RRM}$			$T_{j} = 125^{\circ}C$		8		7 1
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 30A \\ V_R = 800V \\ di/dt = 1000A/\mu s$			160		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_j = 125$ °C	2550		nC	
$I_{RRM}$	Reverse Recovery Current				28		A

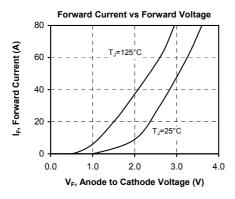
Thermal and package characteristics

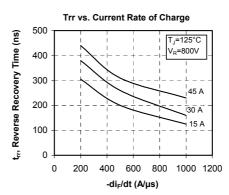
Symbol	Characteristic			Min	Typ	Max	Unit
$R_{\text{thJC}}$	Junction to Case Thermal Resistance					1.2	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range			-40		175	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

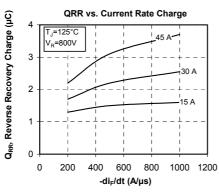


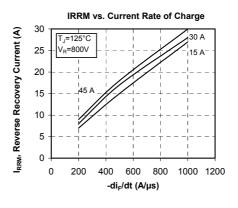
### **Typical Performance Curve**

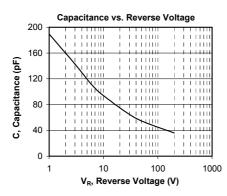


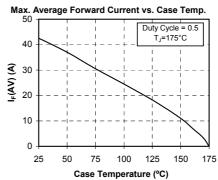






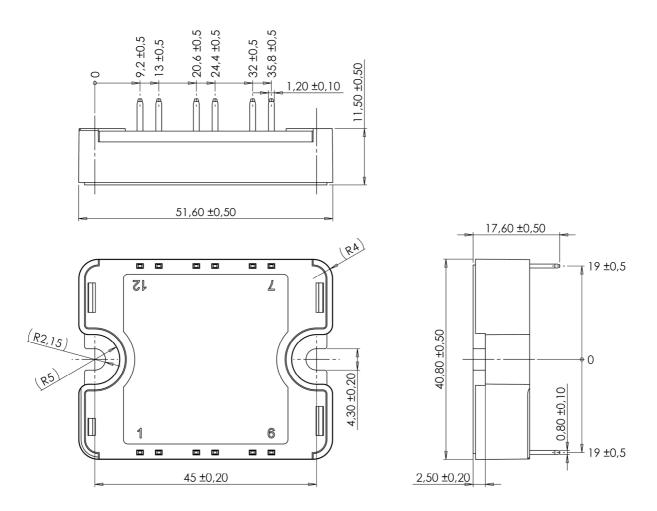








### SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com



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